Table 1

	VCG	VD	vs	mechanism
writing	10V	8∨	ov	hot electron injection
erasing	-20V	float	ov	tunnel current drawing
reading-out	5V	1V	ov	

Table 2

	VCG	VD	vs	mechanism
writing	0∨	float	-10V	tunnel current injection
erasing	-15V	float	ov	tunnel current drawing
reading-out	7∨	1V	ov	

Table 3

	VCG	VD	vs	mechanism
writing "1"	10V		ov	hot electron injection
writing "2"	11V	8∨		
writing "3"	12V			
erasing	-20V	float	ov	tunnel current drawing
reading-out "0"	10.5V / 5V		ov	
reading-out "1"	10.5V / 5V			
reading-out "2"	10.5V / 11.5V	1 1 1 1		
reading-out "3"	10.5V / 11.5V			